

Vishay Semiconductors

Silicon Rectifier Diodes, (Stud Version) 15 A



FEATURES

- · Low thermal impedance
- High case temperature



- · Excellent reliability
- · Maximum design flexibility
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

PRIMARY CHARACTERISTICS		
I _{F(AV)}	15 A	
Package	DO-5 (DO-203AB)	
Circuit configuration	Single	

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		15 ⁽¹⁾	А	
I _{F(AV)}	T _C	150 ⁽¹⁾	°C	
I _{FSM}	50 Hz	239	^	
	60 Hz	250 ⁽¹⁾	A	
l²t	50 Hz	286	A2-	
	60 Hz	260	A ² s	
I ² √t		3870	A²√s	
V _{RRM}	Range	50 to 600	V	
T _J		-65 to +175	°C	

Note

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS			
TYPE NUMBER	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = -65 °C TO 175 °C) V	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = -65 °C TO 175 °C)	
VS-1N3208	50 ⁽¹⁾	50 ⁽¹⁾	
VS-1N3209	100 (1)	100 ⁽¹⁾	
VS-1N3210	200 ⁽¹⁾	200 ⁽¹⁾	
VS-1N3211	300 (1)	300 (1)	
VS-1N3212	400 (1)	400 (1)	
VS-1N3213	500 ⁽¹⁾	500 ⁽¹⁾	
VS-1N3214	600 (1)	600 ⁽¹⁾	

• Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g. 1N3208R, 1N3209R

⁽¹⁾ JEDEC® registered values

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FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	1	180° sinusoidal conduction		15 ⁽¹⁾	Α
at case temperature	I _{F(AV)}			150 ⁽¹⁾	°C
Maximum peak one cycle non-repetitive surge current	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	239	Α
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		250 ⁽¹⁾	
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with V _{RRM} applied following surge = 0	284	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		297	
10. 6 . 6 .		t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = 150 ^{\circ}\text{C}$	286	A ² s
Maximum I ² t for fusing	l ² t	t = 8.3 ms		260	
Maximum I ² t for individual		t = 10 ms	With $V_{RRM} = 0$ following surge, initial $T_J = 150 ^{\circ}\text{C}$	403	
device fusing		t = 8.3 ms		368	
Maximum $I^2\sqrt{t}$ for individual device fusing	I ² √t ⁽²⁾	t = 0.1 ms to 10 ms, V _{RRM} = 0 following surge		3870	A²√s
Maximum forward voltage drop	V_{FM}	$I_{F(AV)} = 15 \text{ A (47.1 A peak)}, T_C = 150 ^{\circ}\text{C}$ 1.5 $^{(1)}$ V		V	
Maximum average reverse current	I _{R(AV)}	Maximum rated $I_{F(AV)}$ and $T_C = 150$ °C 10 $^{(1)}$ mA		mA	

Notes

- (1) JEDEC® registered values
- (2) I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

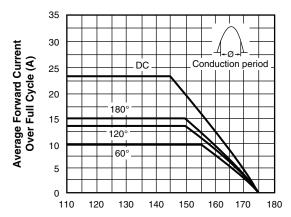
THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to 175 ⁽¹⁾	°C	
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	0.65	°C/W	
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	C/VV	
		Not lubricated thread, tighting on nut (2)	3.4	(30)	
Maximum allowable mounting torque (+0 %, -10 %)		Lubricated thread, tighting on nut (2)		.3 (20)	
		Not lubricated thread, tighting on hexagon (3)	4.2	(37)	
		Lubricated thread, tighting on hexagon (3)	3.2	(28)	
Maight			28.5	g	
Weight			1	oz.	
Case style		JEDEC®	DO-5 (DO-203AB)		

Notes

- (1) JEDEC® registered values
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

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Maximum Allowable Case Temperature (°C)

Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature

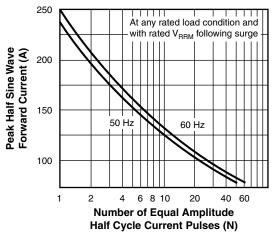
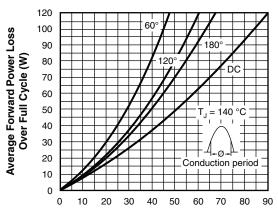
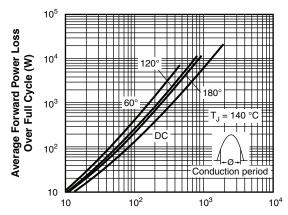


Fig. 2 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses



Average Forward Current Over Full Cycle (A)

Fig. 3 - Maximum Low Level Forward Power Loss vs. Average Forward Current



Average Forward Current Over Full Cycle (A)

Fig. 4 - Maximum High Level Forward Power Loss vs. Average Forward Current

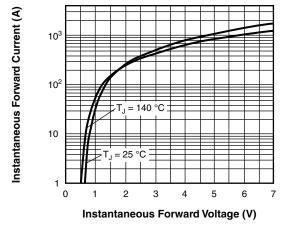


Fig. 5 - Maximum Forward Voltage vs. Forward Current

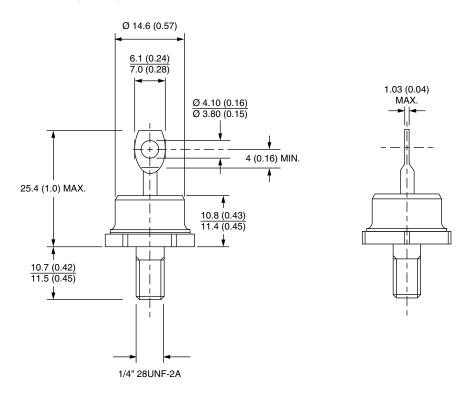
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95360	

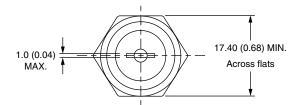


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DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)







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